Site Occupancy of Ti⁴⁺-Doped ZrGeO₄ and HfGeO₄ **Probed by Raman Spectroscopy**

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Received April 10, 1997. Revised Manuscript Received August 11, 1997[®]

Isostructural HfGeO₄ and ZrGeO₄, activated with Ti^{4+} , yield blue luminescence when irradiated with X-rays. An adequate understanding of the observed blue luminescence requires the determination of the site occupancy and the local Ti⁴⁺ environment; i.e., the site symmetry. Raman spectroscopy has been used to probe the chemical bonding and crystal structure of metal germanates. The group vibrational modes of $MGeO_4$ (M = Zr, Hf) are assigned through shifts of the Raman bands in a $Hf_{1-x}Zr_xGeO_4$ solid solution series and through the application of the Raman polarization selection rules to micro-Raman spectra of single crystals. Macro-Raman spectra of undoped and titanium-activated $ZrGeO_4$ and HfGe O_4 powder samples and micro-Raman spectra of single crystals of ZrGeO₄:Ti⁴⁺ confirm that Ti^{4+} occupies the Ge⁴⁺ site in ZrGeO₄ and in HfGeO₄. In addition, not all of the GeO₄⁴⁻ modes are strongly affected by Ti^{4+} doping, even though all of the modes most affected by Ti^{4+} doping arise from the GeO_4^{4-} group. It is observed that Ti^{4+} substitution for Ge^{4+} significantly affects Raman bands arising from GeO44- rotational and bending motions about the *c*-axis, within the *ab*-plane.

Introduction

Under X-ray irradiation, HfGeO₄ exhibits a strong ultraviolet emission,¹ and, upon activation with Ti⁴⁺, a broad blue luminescence centered at 425 nm is observed.² The high X-ray absorption of the material (p = 8.5 g/cm³), in combination with efficient luminescence, establishes the compound as a promising X-ray phosphor. Hafnium and zirconium germanate crystallize in the scheelite structure (Figure 1). Chains of eight-coordinate Hf4+ cations traverse the *ab*-plane in the directions of the respective axes, while isolated GeO₄⁴⁻ tetrahedra alternate with the Hf^{4+} cations in the *c* direction. The GeO₄⁴⁻ moieties are distorted; exhibiting compression in the *c* direction. An adequate understanding of the observed blue luminescence requires the determination of the local titanium environment, i.e., the site symmetry. Lattice parameter and elemental analyses of compositions in HfGeO4:Ti4+ solid solution indirectly suggest that the bulk of the Ti⁴⁺ activator resides at the tetrahedral site.³

Zircon, ZrSiO₄, is related structurally to scheelite phases of HfGeO₄ and ZrGeO₄ in that each contain only 8-fold and 4-fold coordination spheres. The distinction between the structures lies in the three-dimensional linkage of the two sites. The site symmetry of impurities in the zircon phase has been examined by ESR and electronic spectroscopy with considerable effort directed to the location of $V^{4+,4-6}$ Andres et al.⁷ and Beltran et al.8 applied ab initio perturbed ion calculations to pro-

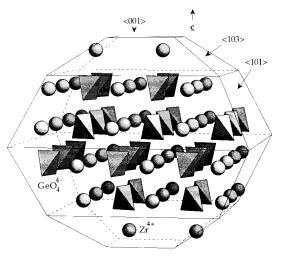


Figure 1. Habit and crystal structure of MGeO₄.

pose that V⁴⁺ lies in the eight-coordinate site in ZrSiO₄. Chandley et al.⁹ used lattice-energy calculations, electron microprobe, and X-ray diffraction to conclude that V⁴⁺ resides at both the tetrahedral and 8-fold sites in ZrSiO₄ but only at the tetrahedral site in ZrGeO₄. The authors also suggest that Tb⁴⁺ dopes into the Zr⁴⁺ site in ZrGeO₄. In a subsequent paper, Andres et al. extended their ab initio perturbed-ion modeling to V4+ and Tb⁴⁺ in ZrGeO₄.¹⁰ Pope and West summarized the FT Raman spectra of a number of inorganic tetrahedral ions over the temperature range 77-473 K.¹¹

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Ti⁴⁺-Doped ZrGeO₄ and HfGeO₄

A convenient method for probing the chemical bonding and crystal structure of metal oxides is Raman spectroscopy. Early studies of compounds having the scheelite structure, such as CaWO₄, SrWO₄, CaMoO₄, and SrMoO₄, demonstrated that Raman bands could be reasonably assigned to internal and external lattice vibrational modes.^{12,13} The distinction pertains, in this case, to the vibrational motions of the isolated transition metal-oxide tetrahedra. Those vibrational motions of the tetrahedra in which the center of mass does not move are regarded as internal modes; i.e., the vibrational motions approximate those of an isolated tetrahedron. In contrast, external modes are assigned to translational movement of the metal cation or tetrahedron or rotational motion of the tetrahedron. More recently, work has been performed on scheelite tungstates relating the wavenumbers of internal stretching modes to W–O bond strengths and lengths.¹⁴ Raman polarization selection rules, in conjunction with internal and external mode assignments, have been applied to study the effects of mixed cations on bonding and crystal structure in MIMIII(XO₄)₂ compounds.^{15–17} Raman spectroscopy has been used to study the scheelite crystal LiYF₄, which is of technological interest as a laser host crystal for lanthanides.¹⁸ A Raman study of Nd³⁺-doped GdLiF₄ and YLiF₄ has been performed, but the authors did not report any effects of Nd³⁺ doping on the lattice vibrational modes.¹⁹

Previous studies of metal germanates by vibrational (Raman and infrared) spectroscopies have been reported.^{20,21} In this study, we were able to assign the group vibrational modes of $MGeO_4$ (M = Zr, Hf) through shifts of the Raman bands in a Hf_{1-x}Zr_xGeO₄ solid solution series and through the application of the Raman polarization selection rules to micro-Raman spectra of single crystals. Macro-Raman spectra of undoped and titanium-activated MGeO₄ powder samples and micro-Raman spectra of single crystals of ZrGeO₄: Ti^{4+} confirm that Ti^{4+} occupies the Ge^{4+} site in ZrGeO₄ and in HfGeO₄. In addition, we find that whereas all of the modes most affected by Ti⁴⁺ doping are those arising from the GeO_4^{4-} group, not all of the GeO_4^{4-} modes are strongly affected by Ti^{4+} doping. Specifically, we conclude that Ti^{4+} substitution for Ge^{4+} significantly affects Raman bands arising from rotational and bending motions of the GeO_4^{4-} group about the *c*-axis, within the *ab*-plane. We apply group and molecular orbital theory to explain this effect.

Experimental Section

Powder diffraction patterns were obtained with an Enraf Nonius FR552 Guinier camera with Cu K α_1 radiation. Films were digitized using a scanning densitometer, and lattice

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parameters determined by the least-squares method with a modified version of the Novak and Colville²² templates.

The details of the preparation of the solid solution Hf_{1-x}Zr_xGeO₄:Ti samples have been described.²³ The samples were prepared from aqueous solutions containing the appropriate molar ratios of HfOCl2+8H2O and ZrOCl2+8H2O (Teledyne Wah Chang Albany; RGS), and either (NH₄)₂TiO-(C₂O₄)₂·H₂O (Johnson-Matthey), or an aqueous TiCl₄ (20% HCl, Aldrich) solution, as the Ti^{4+} source. GeO_2 (Eagle-Picher, 99.999%) was added as a solid, and the coprecipitation attained through the slow addition of concentrated ammonium hydroxide. After collection, washing, and drying at 95 °C, the amorphous hydrous metal oxide gel was normally combined with a Li_2SO_4 (Johnson-Matthey, 99.7%) flux, and fired in an alumina crucible in air at 1100 $^\circ C$ for 6 $h.^{24}$ The resulting ingot was washed in hot distilled water to remove the flux.

Powder diffraction of the collected and dried material showed only the scheelite phase, with linear changes in lattice parameters across each solid solution series. Elemental analysis of the HfGeO4:Ti samples showed complete incorporation of Ti⁴⁺, with no significant flux impurities.²⁵

The single crystals were prepared from a Li₂MoO₄·2MoO₃ flux containing 2 wt % ZrO₂ and 5-fold excess of GeO₂. Titanium was added as TiO₂ at 100 and 200 mol % of the ZrO₂ value. Platinum crucibles were used, and the charges were cooled at a rate of 4 °C/h from 1300 to 900 °C in a vertical molybdenum disilicide tube furnace. The molten charges were air-quenched from 900 °C, and the crystals extracted after treatment with hot water and hot concentrated ammonium hydroxide solution. The crystals were of high optical quality, usually assuming the crystal habit shown in Figure 1, and ranged in size from 0.5 to 1.0 mm.

Larger crystals of ZrGeO₄ (up to 5 mm) were grown using the technique of accelerated crucible rotation26 (ACRT) in combination with a 1 °C/h cooling rate. The lattice parameters observed for increasing titanium levels are consistent with those found in $\rm ZrGeO_4:Ti^{4+}$ powder samples. By comparison with similar cell volume changes in the HfGeO₄:Ti⁴⁺ series, the crystals prepared with 100 and 200 mol % TiO₂ addition have, respectively, ~ 4 and ~ 12 mol % Ti⁴⁺ incorporation. Energy-dispersive X-ray analysis of two of the high Ti⁴⁺ content crystals indicated 8-9 mol % Ti4+ incorporation and no significant molybdenum incorporation.²⁵

Macro-Raman spectra of the powder samples were obtained using a SPEX 1403 double monochromator with 1800 grooves/ mm holographically ruled gratings. The detector is a highsensitivity GaAs photocathode RCA C31034 photomultiplier tube. Spectra of powder samples held in melting point capillaries were obtained from a 90° scattering configuration using 100 mW of 488.0 nm excitation, measured at the sample. Spectra were generated by scanning from 100 to 1000 cm⁻¹ in 1.0 cm⁻¹ increments at 2.0 s integration time with the slits set to 200 µm/280 µm/280 µm/200 µm.

Micro-Raman spectra were obtained using an Instruments SA S3000 spectrometer with 488.0 nm excitation in conjunction with an EEV Class One #15-11 CCD detector, and slits set to 200 μ m/4.09 mm/200 μ m. Also, scanned spectra were acquired using 647.1 nm excitation in conjunction with a Hamamatsu R943-02 photomultiplier tube (PMT) with the slits set to 400 μ m/480 μ m/480 μ m/400 μ m. The spectra obtained with the CCD were acquired over a 10 s read time, whereas those obtained using the PMT were acquired by scanning from 100 to 900 cm⁻¹ in 1.0 cm⁻¹ increments at 2.0 s integration time. Micro-Raman spectroscopy was performed by focusing the laser beam with an Olympus MS Plan 50 (0.80

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NA) objective at various positions on the $\langle 001 \rangle$ and $\langle 103 \rangle$ faces of the ZrGeO₄ and ZrGeO₄:Ti⁴⁺ single crystals. The laser polarization remained fixed relative to the optical instrumentation; the crystal orientation relative to the incident polarization was controlled using a microscope rotational stage.

Results and Discussion

The transition-metal germanates, MGeO₄ (here M = Zr or Hf), are tetragonal and belong to the C_{4h} crystal point group. The irreducible representations of the optical phonons derived from a group theoretical treatment are

$$\Gamma_{\text{optical}} = 3A_g(\mathbf{R}) + 5B_g(\mathbf{R}) + 5E_g(\mathbf{R}) + 4A_u(\mathbf{IR}) + 3B_u(\text{inactive}) + 4E_u(\mathbf{IR})$$
(1)

where IR, R, and inactive represent infrared active, Raman active, and inactive modes, respectively. Furthermore, site group analysis predicts the following external translational and librational modes:

$$\Gamma_{\text{trans}} = \Gamma_{\text{Zr}} + \Gamma_{\text{Ge}} = 2B_g(\mathbf{R}) + 2E_g(\mathbf{R}) + 2A_u(\mathbf{IR}) + 2E_u(\mathbf{IR})$$
(2)

$$\Gamma_{\rm lib} = A_g(\mathbf{R}) + E_g(\mathbf{R}) + B_u(\text{inactive}) + E_u(\mathbf{IR}) \quad (3)$$

$$\Gamma_{\text{ext}} = \Gamma_{\text{trans}} + \Gamma_{\text{lib}} = A_g(\mathbf{R}) + 2B_g(\mathbf{R}) + 3E_g(\mathbf{R}) + 2A_u(\mathbf{IR}) + B_u(\text{inactive}) + 3E_u(\mathbf{IR})$$
(4)

The remaining internal modes can be attributed to the vibrational motions of the GeO₄ group:

$$\Gamma_{\text{int}} = \Gamma_{\text{optical}} - \Gamma_{\text{ext}} = 2A_g(\mathbf{R}) + 3B_g(\mathbf{R}) + 2E_g(\mathbf{R}) + 3A_u(\mathbf{IR}) + 2B_u(\text{inactive}) + 2E_u(\mathbf{IR})$$
(5)

The polarizability tensors for the Raman active modes are:

$$A_{g} = \begin{pmatrix} a & 0 & 0 \\ 0 & a & 0 \\ 0 & 0 & b \end{pmatrix}, \qquad B_{g} = \begin{pmatrix} c & d & 0 \\ d & -c & 0 \\ 0 & 0 & 0 \end{pmatrix}, \\ E_{g} = \begin{pmatrix} 0 & 0 & e \\ 0 & 0 & f \\ e & f & 0 \end{pmatrix}, \begin{pmatrix} 0 & 0 & -f \\ 0 & 0 & e \\ -f & -e & 0 \end{pmatrix}$$
(6)

Our study included Raman analyses of both powders and single crystals of ZrGeO₄ and Ti⁴⁺-doped ZrGeO₄. A Raman spectrum obtained from a powder sample of ZrGeO₄ is shown in Figure 2. The spectrum is comparable to those published in previous reports, although some of our band assignments differ from those of Vandenborre and co-workers.^{20,21} (We will address this later in the paper.) The inset in Figure 2 shows portions of ZrGeO₄ and ZrGeO₄:Ti⁴⁺ (2.5%) spectra. Certain Raman bands of ZrGeO₄:Ti⁴⁺ (2.5%) powder are clearly shifted relative to the corresponding bands of ZrGeO₄. Of those shown here, the band at 293 cm⁻¹ is strongly shifted whereas the band at 305 $\rm cm^{-1}$ is only modestly so. Other bands, such as that at 255 cm⁻¹, show no movement with Ti⁴⁺ doping. The ZrGeO₄ Raman bands most affected by Ti4+ doping, manifested as band shifts in the ZrGeO₄:Ti⁴⁺ (2.5%) powder spectrum, are at 294, 378, 406, and 565 cm⁻¹. Presumably the bands affected are those whose vibrational modes involve the site occupied by Ti⁴⁺. One of the primary goals of this

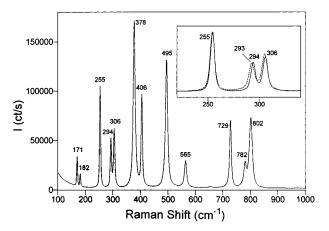


Figure 2. Powder Raman spectrum of $ZrGeO_4$. The inset shows a portion of spectra of $ZrGeO_4$ (solid) and $ZrGeO_4$:Ti⁴⁺ (2.5%) (dashed).

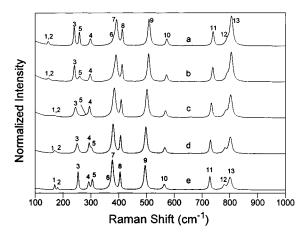


Figure 3. Raman spectra of the $Hf_{1-x}Zr_xGeO_4$ solid solution series: (a) x = 0; (b) x = 0.1; (c) x = 0.5; (d) x = 0.8; (e) x = 1.0.

research was to identify the site occupancy of Ti^{4+} -doped metal germanates. Therefore, a correct assignment of the vibrational modes is crucial to the determination of Ti^{4+} site occupancy.

Hf1-xZrxGeO4 Solid Solution Series. One approach that we have taken to assign the group vibrational modes of ZrGeO₄ is through shifts of the Raman bands in a $Hf_{1-x}Zr_xGeO_4$ solid solution. Raman spectra of a Hf_{1-x}Zr_xGeO₄ solid solution series are shown in Figure 3. The 13 Raman bands of ZrGeO₄ have been numbered to more easily follow their shift as the stoichiometry progresses from ZrGeO₄ to HfGeO₄. In general, the external modes can be expected to appear at lower wavenumbers, whereas the internal modes can be found at higher wavenumbers. Inspection of Figure 3 reveals that some bands shift to lower wavenumbers as Hf⁴⁺ is substituted for Zr⁴⁺, whereas others shift to higher wavenumbers. For example, in the region below 450 cm⁻¹ we see that bands 1, 2, 3, and 5 shift to lower wavenumbers as the stoichiometry progresses from $ZrGeO_4$ to $HfGeO_4$; however, bands 4 and 6–13 shift to higher wavenumbers. Plots of the Raman band shifts as a function of $Hf_{1-x}Zr_xGeO_4$ chemical composition are shown in Figure 4a,b.

The band shifts can be explained by changes in atomic mass and chemical bonding force constants. The atomic mass of Zr is 91.2, whereas that of Hf is 178.5. Therefore, those Raman bands due to external modes involving M should shift to lower wavenumbers upon

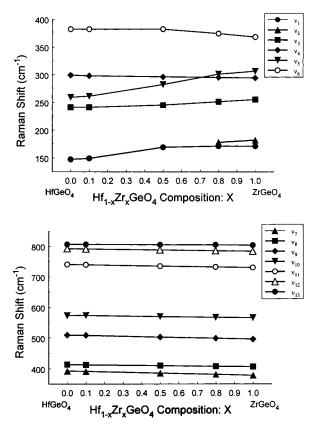


Figure 4. Plots of Raman shift as a function of stoichiometry for (a) Γ_{ext} and (b) Γ_{int} .

substitution of Hf⁴⁺ for Zr⁴⁺. Given that the mass of Ge at 72.6 is significantly lower than that of Zr, we can expect that the two lowest wavenumber bands, 1 and 2 in Figure 3, constitute the Γ_M (M = Zr, Hf) mode set. Here we assume that the magnitude of any increases in the bond strengths, and therefore the vibrational force constants, of the MO₈ group are offset by the more significant change in mass accompanying the substitution of Hf^{4+} for Zr^{4+} . Also, we can expect that any changes in bond strengths of the MO₈ group would also affect the Γ_{Ge} bands as well. The ν_3 and ν_5 bands, which we attribute to Γ_{Ge} , also shift to lower wavenumbers upon substitution of Hf⁴⁺ for Zr⁴⁺. The net result of M substitution is that all four of the Γ_{trans} bands shift to lower wavenumbers. We justify our assignment of v_1 and ν_2 as Γ_M and ν_3 and ν_5 as Γ_{Ge} based on the mass argument described above. Furthermore, the greater Raman scattering strength (greater polarizability) of v_3 and v_5 relative to that of v_1 and v_2 is indicative of greater covalency, which we would expect for the GeO_4^{4-} group. The v_4 and v_6 bands, which shift to higher wavenumbers upon substitution of Hf⁴⁺ for Zr⁴⁺, can be attributed to Γ_{lib} , thereby completing our assignment of Γ_{ext} . The remaining bands, v_7 through v_{13} , constitute the set of Γ_{int} . A complete assignment of the group modes for ZrGeO₄ is shown in Table 1.

A shift to lower wavenumbers can be expected for Γ_M bands as Hf^{4+} is substituted for Zr^{4+} . However, the mass change accompanying the metal substitution would not have the same direct effect on vibrational modes associated with the GeO_4^{4-} group. The effect of the substitution of Hf^{4+} for Zr^{4+} on vibrational modes associated with the GeO_4^{4-} group is a slight shifting of the Γ_{int} bands to higher wavenumbers. In the GeO_4^{4-} group, changes in vibrational force constants would now

 Table 1. Assignment of Group Modes from Hf1-xZrxGeO4

 Solid Solutions^{a,b}

mode assignment	Raman band (cm ⁻¹)	mode assignment	Raman band (cm ⁻¹)	
Γ_{Zr}	171 (v ₁)	$\Gamma_{\rm int}$	406 (v ₈)	
Γ_{Zr}	182 (v ₂)	Γ_{int}	495 (v ₉)	
Γ_{Ge}	255 (v ₃)	Γ_{int}	565 (v ₁₀)	
Γ_{lib}	294 (v ₄)	Γ_{int}	729 (v ₁₁)	
Γ_{Ge}	306 (<i>v</i> ₅)	Γ_{int}	782 (v ₁₂)	
Γ_{lib}	368 (ν_6)	Γ_{int}	802 (v ₁₃)	
Γ_{int}	378 (v ₇)			

 a The numbers in parentheses are the band numbers from Figure 3. b The Raman band shifts are for $ZrGeO_4$ only.

 Table 2. Mode Assignment of ZrGeO4 Bands Most

 Affected by Ti⁴⁺ Doping

	J 1 8
$ ilde{ u}$ (cm ⁻¹)	mode assignment
$\begin{array}{c} 294 \ (\nu_4) \\ 378 \ (\nu_7) \\ 406 \ (\nu_8) \\ 565 \ (\nu_{10}) \end{array}$	$\Gamma_{ m lib} ({ m GeO_4}) \ \Gamma_{ m int} ({ m GeO_4})$

be the dominant factor affecting Raman band shifts because the constituent atoms, and therefore their masses, remain the same. That the vibrational force constants for the GeO_4^{4-} group should be greater in HfGeO₄ than in ZrGeO₄ is reasonable given the slightly smaller cell volume, and presumably shorter bond lengths, of HfGeO₄. (The cell volumes of ZrGeO₄ and HfGeO₄ are 249.5 and 246.8 Å³, respectively.) Accordingly, we have qualitatively characterized the Γ_{int} Raman bands as arising primarily from the GeO₄⁴⁻ groups.

The group mode assignments of the Raman bands most affected by Ti⁴⁺ are shown in Table 2. All of the modes most affected by Ti⁴⁺ doping are those arising from the GeO_4^{4-} group, strongly suggesting that Ti^{4+} occupies the Ge^{4+} site. An interesting aspect of the results is that whereas all of the modes most affected by Ti⁴⁺ doping are those arising from the GeO₄⁴⁻ group, not all of the GeO₄⁴⁻ modes are equally affected by Ti⁴⁺ doping. We address and explain this particular point later in the paper. Also, in a later section we will discuss the results obtained by polarized micro-Raman spectroscopy and show that the band assignments based upon the series of $Hf_{1-x}Zr_xGeO_4$ solid solutions are consistent with those based upon the application of the Raman polarization selection rules to single crystals of MGeO₄. Furthermore, the polarized micro-Raman results will also point to the Ge⁴⁺ site as the one occupied by the Ti⁴⁺ dopant.

It is worthwhile to elaborate on the value of a solid solution series in properly making Raman band assignments. Note that whereas ν_1 and ν_2 are clearly resolved in the spectrum of ZrGeO₄, they are not resolved in the spectrum of HfGeO₄ and could easily be incorrectly assigned as a single band. Likewise, an even more subtle example is the combination of ν_6 and ν_7 . The deconvolved ν_6 and ν_7 from the spectrum of HfGeO₄ appear at 382.0 and 392.0 cm⁻¹ and have 100% and 55% Lorentzian (45% Gaussian) line shape, respectively (Figure 5). Band deconvolution was performed on the remainder of the spectral set, holding constant the percent Lorentzian character for each band as determined by the results of the operation on HfGeO₄. The results of that operation are shown in Table 3.

The trend that we observe is that band separation decreases with mixing of the metals and in fact achieves

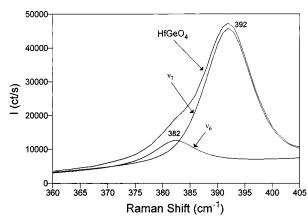


Figure 5. Deconvolution of v_6 and v_7 from HfGeO₄.

Table 3. Band Deconvolution from $Hf_{1-x}Zr_xGeO_4$ Solid Solutions

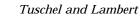
compound	$\nu_{6} \ ({\rm cm^{-1}})$	$\nu_7 ({\rm cm}^{-1})$	I_{6}/I_{7}^{a}
HfGeO ₄	382	392	0.212
Hf _{0.9} Zr _{0.1} Ge _{O4}	382	391	0.231
Hf _{0.5} Zr _{0.5} GeO ₄	382	385	0.459
Hf _{0.2} Zr _{0.8} GeO ₄	374	381	0.245
ZrGeO ₄	368	378	0.056

^a I represents the integrated intensity under the band.

its lowest value of 3 cm⁻¹ for Hf_{0.5}Zr_{0.5}GeO₄. As stoichiometry is again achieved, at ZrGeO₄ the band separation is 10 cm⁻¹, the same as that for HfGeO₄. However, notice that the value of the relative intensities of v_6 and v_7 , I_6/I_7 , has reached its lowest level in ZrGeO₄. Consequently, the moderate shoulder present in the HfGeO₄ spectrum is absent in that of ZrGeO₄, and so v_6 can easily go undetected. Without the solid solution series, v_6 could not readily be detected in the ZrGeO₄ spectrum, and the observed number of bands would fall one short of the number predicted by group theory.

The changes in the band separation of ν_6 and ν_7 and their relative intensities (I_6/I_7) are noteworthy given that ν_6 and ν_7 have been assigned to $\Gamma_{\rm lib}$ and $\Gamma_{\rm int}$, respectively, and that the librational modes have been attributed to rotational motions of the GeO₄^{4–} group.¹³ Inspection of Figure 3 reveals that ν_4 , the other member of the set constituting $\Gamma_{\rm lib}$, does not show a decrease in relative intensity comparable to that of ν_6 with compositional change from Hf_{0.5}Zr_{0.5}GeO₄ to ZrGeO₄.

Powder samples of HfGeO₄ doped with 1, 2, 4, and 6% Ti⁴⁺ were prepared, and Raman spectra of the entire set were acquired for comparison with those obtained from ZrGeO₄:Ti⁴⁺. As observed in the spectra of Zr-GeO₄:Ti⁴⁺, some HfGeO₄:Ti⁴⁺ bands are moderately shifted, some strongly shifted, and others show no movement with Ti⁴⁺ doping. All of the aforementioned effects can be seen in the partial spectra shown in Figure 6. There is no movement of v_3 with Ti⁴⁺ doping, whereas v_5 shows modest movement and v_4 is strongly shifted. Also, v_4 manifests a greater intensity change relative to v_3 than does v_5 . Plots of HfGeO₄ and HfGeO₄: Ti^{4+} (6%) in the spectral region corresponding to the region in the ZrGeO₄ spectrum most affected by Ti⁴⁺ doping are shown in Figure 7. The bands are labeled for easy comparison with the $ZrGeO_4$:Ti⁴⁺ data. We find that the HfGeO₄ bands affected by Ti⁴⁺ doping correspond to the most strongly affected ZrGeO₄:Ti⁴⁺ bands, and these are listed in Table 4. As for ZrGeO₄: Ti⁴⁺, we again observe that all of the modes most



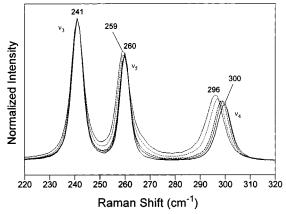


Figure 6. Powder Raman spectra of $HfGeO_4$ (solid), $HfGeO_4$: Ti⁴⁺ (1%) (dotted), $HfGeO_4$:Ti⁴⁺ (2%) (dashed), $HfGeO_4$:Ti⁴⁺ (4%) (dash-dot), and $HfGeO_4$:Ti⁴⁺ (6%) (dash-dot-dot).

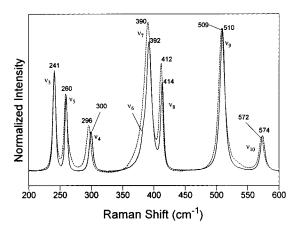


Figure 7. Powder Raman spectra of $HfGeO_4$ (solid) and $HfGeO_4:Ti^{4+}$ (6%) (dashed).

Table 4. Mode Assignment of MGeO₄ Bands Most Affected by Ti^{4+} Doping

HfGeO ₄ $\tilde{\nu}$ (cm ⁻¹)	$ZrGeO_4 \tilde{\nu}$ (cm ⁻¹)	mode assignment
$\begin{array}{c} 300 \ (\nu_4) \\ 392 \ (\nu_7) \\ 414 \ (\nu_8) \\ 574 \ (\nu_{10}) \end{array}$	294 (ν_4) 378 (ν_7) 406 (ν_8) 565 (ν_{10})	$\Gamma_{ m lib} ({ m GeO_4}) \ \Gamma_{ m int} ({ m GeO_4})$

affected by Ti⁴⁺ doping are those arising from the GeO_4^{4-} group, consistent with Ti⁴⁺ occupying the Ge⁴⁺ site in ZrGeO₄ and in HfGeO₄. It is noteworthy that, in HfGeO₄ as well as in ZrGeO₄, not all of the bands arising from GeO_4^{4-} vibrational motions are equally affected by Ti⁴⁺ doping. We address this point in the following section by first identifying the symmetries of all the bands constituting the MGeO₄ Raman spectrum.

Polarized Micro-Raman Spectroscopy of Zr-GeO₄:Ti⁴⁺ Crystals. The application of the Raman polarization selection rules to single crystals of MGeO₄ simplifies the task of vibrational mode assignment. Single crystals of ZrGeO₄, ZrGeO₄:Ti⁴⁺ (~4%), and ZrGeO₄:Ti⁴⁺ (~12%) were grown with a crystal defined by the $\langle 001 \rangle$, $\langle 103 \rangle$, and $\langle 101 \rangle$ faces. Micro-Raman spectra of the $\langle 103 \rangle$ faces of ZrGeO₄ and ZrGeO₄:Ti⁴⁺ single crystals are shown in Figure 8. These crystals were more heavily doped than the previously discussed powder, and so manifest even more dramatic spectral changes. The most significant shifts occur for the bands at (ZrGeO₄ wavenumbers) 294, 378, 405, and 564 cm⁻¹. Also, a band emerges at 647 cm⁻¹ with Ti⁴⁺ doping. This band is apparently the very weak one at 655 cm⁻¹ in

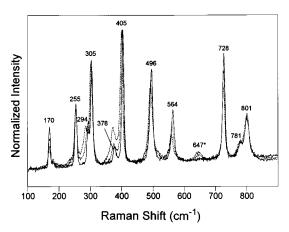


Figure 8. Micro-Raman spectra of the $\langle 103 \rangle$ faces of ZrGeO₄ (solid), ZrGeO₄:Ti⁴⁺ (~4%) (dotted), and ZrGeO₄:Ti⁴⁺ (~12%) (dashed). Band positions are of ZrGeO₄ except for the 647 cm⁻¹ band. The incident polarization is perpendicular to the *c*-axis.

the ZrGeO₄ powder spectrum, and is apparently forbidden when probing the $\langle 103 \rangle$ face. As we observed in the ZrGeO₄:Ti⁴⁺ (2.5%) powder spectrum, Ti⁴⁺ doping does not cause all the bands to shift strongly. Those bands which show modest or no discernible shift are at 170, 255, 305, 496, 728, 781, and 801 cm⁻¹. Those Raman bands from the $\langle 103 \rangle$ face that are most affected with respect to band shift are at 294, 378, 405, and 564 cm^{-1} . That only some of the bands shift as a result of Ti⁴⁺ doping suggests that Ti⁴⁺ is not indiscriminately positioned but rather preferentially occupies specific lattice sites. Last, we note that in addition to band shifts, changes in relative intensities are observed with Ti⁴⁺ doping, thereby indicating changes in chemical bond polarizability. The spectra in Figure 8 are all normalized to the most intense band at 405 cm⁻¹. Relative to the 405 cm⁻¹ band then, the intensities of those bands at 170, 496, 564, and 728 cm^{-1} decrease, whereas those at 378 and 647 cm⁻¹ increase. The relative strengths of bands at 255, 294, 305, 781, and 801 cm⁻¹ remain unchanged. We will comment further on the changes in relative intensity later.

It is not possible to employ group theory in conjunction with polarized Raman analysis of powders to assign Raman bands because secondary and tertiary reflections from the powder generate a depolarized signal. That is not the case for single crystals with smooth, highly reflective faces. Therefore, polarized micro-Raman spectra of a prudently selected single crystal face in conjunction with a powder spectrum allows us to accurately assign the symmetries of the Raman bands. The identification of the symmetries of the bands most affected by Ti⁴⁺ doping provides insight into the changes in chemical bonding induced by doping. The Raman polarizability tensors in eq 6 suggest that a polarized Raman analysis of the $\langle 001 \rangle$ face of a single crystal should allow us to identify the symmetries of all the Raman bands of a powder spectrum. Specifically, using the backscattering configuration, the A_g mode can only be detected from the $\langle 001 \rangle$ face when the analyzer is parallel to the incident polarization. Raman scattering from the A_g mode is forbidden for perpendicular polarization. Also, because the tensor elements α_{xx} and α_{yy} (a) are equal, the intensity of the A_g band should not vary with orientation within the XY plane. See eqs 7 and 8. (Our terminology is such that the X, Y, and Z

$$A_g^0 = \begin{pmatrix} a & 0 & 0 \\ 0 & a & 0 \\ 0 & 0 & b \end{pmatrix} \qquad B_g^0 = \begin{pmatrix} c & d & 0 \\ d & -c & 0 \\ 0 & 0 & 0 \end{pmatrix}$$
(7)

$$A_g^{45} = \begin{pmatrix} a & 0 & 0 \\ 0 & a & 0 \\ 0 & 0 & b \end{pmatrix} \qquad B_g^{45} = \begin{pmatrix} d & -c & 0 \\ -c & -d & 0 \\ 0 & 0 & 0 \end{pmatrix}$$
(8)

axes of the Raman tensors correspond to the a, b, and c crystallographic axes of MGeO₄.) The element α_{zz} , although it may be different from α_{xx} and α_{yy} , cannot be probed in this orientation. Conversely, the B_g modes can be detected with parallel or crossed polarizers, the relative intensities of the two configurations being dependent upon the orientation of the incident polarization. For example, if the incident electric field is polarized parallel to the X-axis, then having the analyzer in the parallel position probes the α_{xx} tensor element (c), whereas the analyzer positioned perpendicular will probe the α_{xy} tensor element (d). Rotating the crystal 45° within the $\langle 001 \rangle$ plane transforms the B_{g} tensor as shown in eqs 7 and 8. At 45°, the analyzer parallel configuration probes the original α_{xy} tensor element (d) and the analyzer perpendicular configuration probes the original α_{xx} tensor element (c). Finally, the E_g modes are forbidden in this experimental orientation, and therefore should not appear in any spectra of the $\langle 001 \rangle$ face. All three vibrational mode symmetries can be differentiated then by probing the $\langle 001 \rangle$ face in the backscattering arrangement.

Parallel and perpendicularly polarized micro-Raman spectra of the (001) face of a ZrGeO₄ single crystal are shown in Figure 9. The incident beam was polarized parallel to one of the ordinary (X or Y) axes of the crystal. Therefore, in this orientation, the A_g bands will be allowed only with the analyzer parallel, but the B_g bands should be allowed in both the parallel and perpendicular configurations. For the experimental results to be in perfect agreement with predictions based on Raman polarization selection rules would require exact alignment of the crystal relative to the incident beam. The crystals analyzed here were not cut and polished and crystal alignment for the micro-Raman study was performed by eye under the microscope. Therefore, some misalignment of the crystal is expected and with it some deviation of the spectra from that expected for a perfectly aligned $\langle 001 \rangle$ face. Consequently, we expect some "leakage" from bands that are nominally forbidden for a given crystal orientation and polarization. The bands at 294, 378, and 802 cm⁻¹ are assigned to A_{ϱ} symmetry. All three of these bands show far greater intensity in the parallel versus the perpendicular configuration. The 378 cm⁻¹ band from the $\langle 001 \rangle$ face is considerably weaker than that of the powder spectrum, and so one could identify it as a forbidden E_g mode "leaking" through due to misalignment, as is the case at 255 and 495 cm^{-1} . However, note that the "leaked" E_g modes at 255 and 495 cm⁻¹ have comparable intensities for parallel and perpendicular configurations, whereas the 378 cm⁻¹ band in the parallel configuration is far stronger than that from the perpendicular arrangement. The reason for the weakness of the 378 cm⁻¹ band detected from the $\langle 001 \rangle$ face is that the α_{zz} tensor element is apparently significantly greater than $\alpha_{xx,yy}$; i.e., b \gg a. The bands at 294, 378, and 802 cm⁻¹ account for all three of the Raman-active A_g modes of

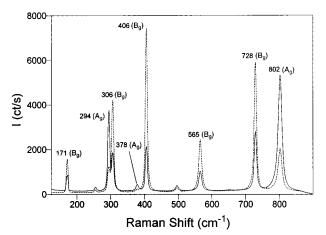


Figure 9. Micro-Raman spectrum of the $\langle 001 \rangle$ face of a ZrGeO₄ single crystal. The incident polarization is parallel to one of the ordinary (*X* or *Y*) axes of the crystal. Analyzer parallel (solid), analyzer perpendicular (dashed).

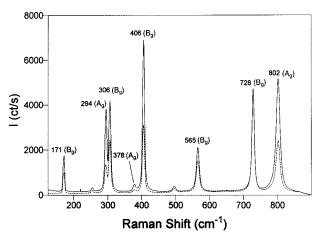


Figure 10. Micro-Raman spectrum of the $\langle 001 \rangle$ face of a ZrGeO₄ single crystal. The incident polarization is 45° with respect to one of the ordinary (*X* or *Y*) axes of the crystal. Analyzer parallel (solid), analyzer perpendicular (dashed).

ZrGeO₄. The remaining bands at 171, 306, 406, 565, and 729 cm⁻¹ are assigned B_g symmetry. That all these bands are more intense in the perpendicular configuration is strong evidence for the B_g assignment. Furthermore, the different parallel vs perpendicular intensity ratios (I_{par}/I_{perp}) for those five bands manifest the different relative tensor element values (dd) in the different modes, and only B_{ρ} modes can do that in this orientation. The bands at 171, 306, 406, 565, and 729 cm^{-1} account for all five of the Raman-active B_g modes of ZrGeO₄. Therefore, by a process of elimination, the remaining two unassigned bands observed in the powder spectrum at 182 and 782 cm⁻¹, along with the two leaked bands at 255 and 495 cm⁻¹, must be assigned a symmetry of E_{g} . That gives us four E_{g} bands, one band short of the number of modes predicted by group theory. The final E_g band must be v_6 at 368 cm⁻¹, which we identified through our study of the Hf_{1-x}Zr_xGeO₄ solid solutions.

Spectra obtained from the $\langle 001 \rangle$ face rotated 45° with respect to the original ordinary axis and within the $\langle 001 \rangle$ plane are shown in Figure 10 and confirm the above assignments. The bands at 294, 378, and 802 cm⁻¹ show the same parallel/perpendicular response as for the experimental arrangement with the incident polarization parallel to an ordinary axis. The invariability

Table 5. Raman Band Assignments of ZrGeO₄^a

this work		Vandenborre et al. ²¹	
$\tilde{\nu}$ (cm ⁻¹)	sym	$\tilde{\nu}$ (cm ⁻¹)	sym
71 (v ₁)	B_{g}	176	E_{g}
82 (v ₂)	$egin{array}{c} B_g \ E_g \end{array}$	186	B_{g}
	0	202	Ĕg
255 (v ₃)	E_{g}	259	A_g^{o}
294 (v4)	A_{g}	298	B_g
$306 (v_5)$	B_{g}	311	$egin{array}{c} E_g \ B_g \ E_g \ A_g \ B_g \ B_g \ E_g \ $
$368 (\nu_6)$	$\vec{E_{g}}$		0
878 (v ₇)	A_{ϱ}^{o}	382	B_{g}
$106 (v_8)$	B_{g}	410	Âg
195 (ν_9)	$\vec{E_{g}}$	500	Ĕg
565 (v ₁₀)	B_{g}	569	B_{g}
29 (v ₁₁)	Eg Ag Bg Eg Bg Bg Bg Eg Bg Bg Eg Ag	732	$egin{array}{c} B_g & A_g & & \ A_g & E_g & & \ B_g & E_g & & \ B_g & & \ B_g & & \ B_g & & \ B_g & & \ A_g & & \ $
$782 (\nu_{12})$	$\vec{E_g}$	786	B_{g}
$302 (\nu_{13})$	Åø	806	Å

 $^a\,{\rm The}$ numbers in parentheses are the band numbers from Figure 3.

of $I_{\text{par}}/I_{\text{perp}}$ with rotation of the $\langle 001 \rangle$ face is the expected response for vibrational modes of A_g symmetry. Conversely, the bands at 171, 306, 406, 565, and 728 cm⁻¹ have different parallel/perpendicular responses from those observed at 0°. At 45° orientation their $I_{\text{par}}/I_{\text{perp}}$ ≥ 1 , whereas at 0° their $I_{\text{par}}/I_{\text{perp}} \leq 1$. This response pattern is consistent with the transformation of the B_g tensor through a 45° rotation. Finally, the two weak bands at 255 and 495 cm⁻¹ have comparable parallel and perpendicular intensities, the same as observed at the 0° orientation. So their response is consistent with our assignment of them as E_g bands that have "leaked through".

Our assignments of the ZrGeO₄ Raman bands are summarized in Table 5. We have included the assignments of Vandenborre and co-workers for comparison. The assignments of Vandenborre et al. were made based upon a normal-coordinate analysis and the Raman spectrum of ZrGeO₄ powder. Comparison of our powder Raman spectrum with that of Vandenborre et al. reveals good agreement with respect to the number and relative intensities of almost all the bands; they are nearly identical. However, we differ on the assignment of some of the mode symmetries and the identification of v_6 at 368 cm⁻¹. In addition, we observe a band at 655 cm⁻¹, not seen by Vandenborre and co-workers, which we attribute to an impurity or defect because of its weakness and the already complete assignment of 13 Ramanactive modes. Also, Vandenborre and co-workers report a band at 202 cm⁻¹, which we cannot detect. Clearly, the most significant disagreement is not with the detection of ZrGeO₄ Raman bands but with their assignments.

Returning to the subject of Ti^{4+} site occupancy, we observe that the Raman bands most affected by Ti^{4+} doping are at 294, 378, 406, and 565 cm⁻¹. We find that these bands, listed in Table 6, constitute a set whose vibrational mode symmetries are consistent with those predicted by eqs 3 and 5 for a librational mode and three internal modes of the GeO_4^{4-} group. Furthermore, our mode assignment based on the symmetry of the affected bands is consistent with that in Table 2 based on the study of the $Hf_{1-x}Zr_xGeO_4$ solid solutions. By having correctly assigned the symmetries of the MGeO_4 Raman bands, including those bands most affected by Ti^{4+} doping, the nature of the Ti^{4+} chemical bonding at the Ge^{4+} lattice site can be more fully characterized. We

Table 6. Mode and Symmetry Assignments of Raman Bands from (103) Face of ZrGeO₄ Most Affected by Ti⁴⁺ Doning^a

 $^{a}\,\mathrm{The}$ numbers in parentheses are the band numbers from Figure 3.

Table 7. Correlation Diagram for the GeO44-MGeO4 Crystal

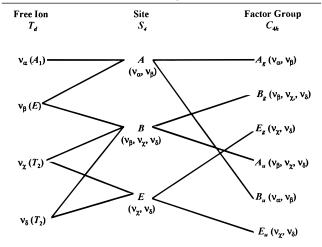


Table 8. Correlation of GeO44-Internal Modes with TdFree Ion

normal vibration	T_d free ion	C_{4h} crystal
sym str	$A_1(\nu_{\alpha})$	$A_{g}(\nu_{\alpha})+B_{u}(\nu_{\alpha})$
sym bend	$E(\nu_{\beta})$	$A_{g}^{'}(\nu_{\beta})+B_{u}(\nu_{\beta})$
		$B_{g}(\nu_{\beta}) + A_{u}(\nu_{\beta})$
asym str	$T_2(\nu_{\chi})$	$B_{g}\left(u _{\chi } ight) +A_{u}\left(u _{\chi } ight)$
		$E_{g}(\nu_{\chi})+E_{u}(\nu_{\chi})$
asym bend	$T_2 (\nu_{\delta})$	$B_{g}(\nu_{\delta}) + A_{u}(\nu_{\delta})$
		$E_{g}(\nu_{\delta}) + E_{u}(\nu_{\delta})$

noted earlier, in the $Hf_{1-x}Zr_xGeO_4$ solid solutions section, that whereas all of the modes most affected by Ti^{4+} doping are those arising from the GeO_4^{4-} group, not all of the GeO_4^{4-} modes are strongly affected by Ti^{4+} doping. Here we apply group and molecular orbital theory to explain this effect.

Note that the affected bands have two common characteristics; i.e., that their Raman tensors have nonzero α_{xx} and α_{yy} tensor elements and that they can be assigned to GeO44- rotation or Ge-O bending motions within the *ab*-plane. The Γ_{lib} mode in Table 6 is a GeO₄^{4–} rotation. We assign the Γ_{int} bands in Table 6 to Ge-O bending motions based on the application of the site group method to correlate the S_4 site symmetry species to a XY_4 free molecule of T_d symmetry. The correlation diagram for the GeO₄⁴⁻ ion in the ZrGeO₄ crystal is shown in Table 7. The free GeO_4^{4-} ion with T_d symmetry has four normal vibrational modes consisting of A_1 (ν_{α}) symmetric stretch, E (ν_{β}) symmetric bend, $T_2(\nu_{\chi})$ asymmetric stretch, and $T_2(\nu_{\delta})$ asymmetric bend. The symmetry of the free GeO_4^{4-} ion is lowered to S_4 in the crystal, and the free ion T_d modes can be correlated to the internal modes of the factor group C_{4h} MGeO₄ crystal. That correlation of the T_d local vibrational modes to C_{4h} phonons is shown in Table 8. In our assignment and correlation of ZrGeO₄ bands to local

 T_d modes, we expect the stretching modes to constitute the highest energy phonons in the spectrum, and indeed the bands at 729 (ν_{11} , B_g), 782 (ν_{12} , E_g), and 802 (ν_{13} , A_g) cm⁻¹ have the appropriate symmetries to correlate to ν_{χ} (*B_g*), ν_{χ} (*E_g*), and ν_{α} (*A_g*), respectively. Referring to Tables 1 and 5, we see that the remaining Γ_{int} bands are at 378 (ν_7 , A_g), 406 (ν_8 , B_g), 495 (ν_9 , E_g), and 565 cm⁻¹ (ν_{10} , B_g), which by symmetry correlate to ν_{β} (A_g), ν_{β} (*B_g*), ν_{δ} (*E_g*), and ν_{δ} (*B_g*), respectively. Of those four $\Gamma_{\rm int}$ bands, the A_g and B_g modes are among those most affected by Ti^{4+} doping. In fact, the bands listed in Table 6 as those most affected by Ti⁴⁺ doping constitute the entire set of combined A_g and B_g bending and rotational modes for ZrGeO₄. There is one E_g bending mode and one E_g rotational mode, both of which are not as strongly affected by Ti⁴⁺ doping. Note, however, that the nonzero E_g tensor elements are α_{xz} , α_{zx} , α_{yz} , and α_{zy} . In contrast, the strongly affected A_g and B_g modes have nonzero α_{xx} , α_{yy} , or α_{xy} (α_{yx}) tensor elements. Therefore, we conclude that Ti⁴⁺ substitution for Ge⁴⁺ significantly affects Raman bands arising from rotational and bending motions of the GeO_4^{4-} group about the *c*-axis, within the ab-plane.

Here we offer an explanation for the effects of Ti⁴⁺ doping on the Raman spectra of ZrGeO₄ and HfGeO₄. The tetrahedral GeO₄^{4–} group is formed by a combination of the oxygen orbitals and sp³ hybridized atomic orbitals from Ge⁴⁺. However, if Ti⁴⁺ is substituted for Ge⁴⁺, the atomic orbitals of the central atom are no longer sp³ hybridized. The 4s (a_1) , 4p (t_2) , 3d (e), and 3d (t₂) atomic orbitals of Ti⁴⁺ will, in a tetrahedral coordination, transform to the molecular orbitals a_1 , t_2 , e, and t₂, respectively. For simplification, we will ignore the distortion at the Ge4+ site from ideal tetrahedral geometry. One a_1 and three t_2 molecular orbitals form σ -bonding orbitals in the tetrahedral structure. In particular, note that the t_2 bonding orbitals are formed by a hybridization of $Ti^{4+} d(t_2)$ and $p(t_2)$ orbitals. The 3d (e) atomic orbitals would transform to e nonbonding molecular orbitals. However, metal oxides readily form π bonds, and the 3d (e) orbitals can form π -bonding orbitals with the ligand in a tetrahedral structure. The excitation of luminescence from Ti4+ may be due to a ligand to metal charge-transfer absorption involving a π (e) back-bonding orbital. If π bonding does occur, then the local electronic structure of the TiO₄⁴⁻ tetrahedron is significantly different from that of the sp³ hybridized GeO₄⁴⁻ tetrahedron. In particular, we could expect the $d_{x^2-y^2}$ (e) orbital involved in π bonding to hinder rotation of TiO_4^{4-} in the *ab*-plane, thereby damping lattice vibrational modes related to the unhindered rotation of the sp³-hybridized GeO₄⁴⁻ tetrahedron. Consequently, Raman bands arising from "GeO44- rotations" should shift and perhaps broaden to lower wavenumber, which is what we observe.

Regarding our interpretation of the spectroscopic effects of Ti^{4+} occupancy of the Ge^{4+} site, it is important to remember that the Raman bands of the MGeO₄ spectrum are due to lattice vibrations, phonons, and are not due to local vibrational modes. Therefore, we have to consider TiO_4^{4-} tetrahedra not in terms of a local motion that produces a discrete band but rather as a point defect perturbing a lattice vibration. In that capacity, one thinks of TiO_4^{4-} point hindered rotations causing specific lattice vibrations, those involving the

rotation or bending of the GeO_4^{4-} group, to function like a damped oscillator. The manifestation of such an effect should be a shifting and broadening of the Raman band to lower wavenumber.

Conclusion

Raman spectroscopy has been used to probe the chemical bonding and crystal structure of MGeO₄:Ti⁴⁺, an efficient X-ray phosphor. The group vibrational modes of MGeO₄ have been assigned based on the movements of the Raman bands in a $Hf_{1-x}Zr_xGeO_4$ solid solution series and through the application of the Raman polarization selection rules to micro-Raman spectra of single crystals. A comparison of the band assignments made by each method reveals that the same results are obtained by either the application of Raman polarization selection rules to single crystals of ZrGeO₄ or through the study of $Hf_{1-x}Zr_xGeO_4$ solid solutions. Thus, we have an internally consistent method for assigning Raman bands to functional groups or substructures in the metal germanates. Furthermore, we have applied the results of our band assignment study to determine the site occupancy of transition metal dopants, in this case Ti⁴⁺, in metal germanates. Macro-Raman spectra of undoped and titanium-activated ZrGeO₄ and HfGeO₄ powder samples and micro-Raman spectra of single crystals of ZrGeO₄:Ti⁴⁺ confirm that Ti^{4+} occupies the Ge^{4+} site in $ZrGeO_4$ and in $HfGeO_4.$

We find that whereas all of the modes most affected by Ti^{4+} doping are those arising from the GeO_4^{4-} group, not all of the GeO44- modes are strongly affected by Ti4+ doping. Specifically, we conclude that Ti⁴⁺ substitution for Ge⁴⁺ significantly affects Raman bands arising from the rotational and bending motions of the GeO_4^{4-} group about the *c*-axis, within the *ab*-plane. We propose an explanation for this effect based on group and molecular orbital theory. When Ti⁴⁺ is substituted for Ge⁴⁺ the atomic orbitals of the central atom are no longer sp³ hybridized, and the 3d (e) orbitals can form π -bonding orbitals with the ligand in a tetrahedral structure. If π bonding does occur, then the local electronic structure of the TiO_4^{4-} tetrahedron is significantly different from that of the sp³-hybridized GeO_4^{4-} tetrahedron. In particular, we could expect the $d_{x^2-y^2}$ (e) orbital involved in π bonding to hinder rotation of TiO₄⁴⁻ in the *ab*-plane, thereby damping lattice vibrational modes related to the unhindered rotation of the sp³ hybridized GeO₄⁴⁻ tetrahedron.

Acknowledgment. P.M.L. would like to thank G.S. Jarrold for his help in sample preparation. Figure 1 was produced with ATOMS by shape software.

CM970205F